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DATE MAILED: 07/09/2004

APPLICATION NO.	FI	LING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
10/635,088	(08/05/2003	Fred Matteson	4905-A-15	7232
33136	7590	07/09/2004		EXAMINER	
WILLIAM C. CAHILL				NGO, NGAN V	
155 PARK ONE 2141 E. HIGHLAND AVENUE				ART UNIT PAPER NUMBER	
PHOENIX, AZ 85016				2814	

Please find below and/or attached an Office communication concerning this application or proceeding.

	Application No.	Applicant(s)					
	10/635,088	MATTESON ET A	MATTESON ET AL.				
Office Action Summary	Examin r	Art Unit					
	Ngan Ngo	2814	p				
The MAILING DATE of this communication ap	pears on the cover sheet with t	h correspond nc ad	dress				
A SHORTENED STATUTORY PERIOD FOR REPL THE MAILING DATE OF THIS COMMUNICATION. - Extensions of time may be available under the provisions of 37 CFR 1. after SIX (6) MONTHS from the mailing date of this communication. - If the period for reply specified above is less than thirty (30) days, a rep - If NO period for reply is specified above, the maximum statutory period - Failure to reply within the set or extended period for reply will, by statute Any reply received by the Office later than three months after the mailine - earned patent term adjustment. See 37 CFR 1.704(b).	I36(a). In no event, however, may a reply ly within the statutory minimum of thirty (30 will apply and will expire SIX (6) MONTHS e, cause the application to become ABAND	be timely filed O) days will be considered timely From the mailing date of this co OONED (35 U.S.C. § 133).					
Status		·					
1) Responsive to communication(s) filed on	 .						
2a) This action is FINAL . 2b) ☐ This	s action is non-final.						
•	Since this application is in condition for allowance except for formal matters, prosecution as to the merits is closed in accordance with the practice under <i>Ex parte Quayle</i> , 1935 C.D. 11, 453 O.G. 213.						
Disposition of Claims							
5) ☐ Claim(s) is/are allowed. 6) ☑ Claim(s) <u>1-14</u> is/are rejected. 7) ☑ Claim(s) <u>15</u> is/are objected to.	4a) Of the above claim(s) is/are withdrawn from consideration. ☐ Claim(s) is/are allowed. ☐ Claim(s) <u>1-14</u> is/are rejected.						
Application Papers							
9)☐ The specification is objected to by the Examiner.							
10)☐ The drawing(s) filed on is/are: a)☐ accepted or b)☐ objected to by the Examiner.							
Applicant may not request that any objection to the drawing(s) be held in abeyance. See 37 CFR 1.85(a).							
Replacement drawing sheet(s) including the correction is required if the drawing(s) is objected to. See 37 CFR 1.121(d). 11) The oath or declaration is objected to by the Examiner. Note the attached Office Action or form PTO-152.							
Priority under 35 U.S.C. § 119							
 12) Acknowledgment is made of a claim for foreign priority under 35 U.S.C. § 119(a)-(d) or (f). a) All b) Some * c) None of: 1. Certified copies of the priority documents have been received. 2. Certified copies of the priority documents have been received in Application No 3. Copies of the certified copies of the priority documents have been received in this National Stage application from the International Bureau (PCT Rule 17.2(a)). * See the attached detailed Office action for a list of the certified copies not received. 							
Attachment(s)	"□·	(0.00)					
1) Notice of References Cited (PTO-892) 4) Interview Summary (PTO-413) 2) Notice of Draftsperson's Patent Drawing Review (PTO-948) Paper No(s)/Mail Date							
3) Information Disclosure Statement(s) (PTO-1449 or PTO/SB/08) Paper No(s)/Mail Date <u>0803</u> . 5) Notice of Informal Patent Application (PTO-152) 6) Other:							

The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

(b) the invention was patented or described in a printed publication in this or a foreign country or in public use or on sale in this country, more than one year prior to the date of application for patent in the United States.

Claims 1 to 10 are rejected under 35 U.S.C. 102(b) as being anticipated by Ito et al.

Ito discloses a semiconductor die comprising a semiconductor substrate diffused with a first material (N-), a buried layer (206), an epitaxial layer (214), a first diffused region (204), a second diffused region (202), and a third diffused region (212).

In re claim 2, figure 27a clearly discloses the zener junction which is a reverse avalanche mode.

In re claim 3, the resistivity of the epitaxial layer is clearly higher than the resistivity of the buried layer.

In re claim 7, the electrostatic discharge circuit disclosed by Ito is clearly a transient voltage suppression device.

In re claim 10, Ito clearly show the first and second external electrical contact on the second diffused region (202) and the third diffused region (212).

The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.

Art Unit: 2814

Claims 11-14 are rejected under 35 U.S.C. 103(a) as being unpatentable over Lie et al in view of Ito et al.

Lie et al disclose a flip chip comprising a transient voltage suppression device.

Note figure 4 of Lie. However Lie does not disclose a particular transient voltage suppression device as claimed by Applicants. Ito disclose a semiconductor die comprising a substrate, a buried layer, an epitaxial layer, a first diffused region, a second diffused region, and a third diffused region to form a transient voltage suppression device. Therefore, it would have been obvious to one of ordinary skill in the art to form the transient voltage suppression device as taught by Ito in a flip chip taught by Lie in order to provide a package for the transient voltage suppression device.

Claim 15 is objected to as being dependent upon a rejected base claim, but would be allowable if rewritten in independent form including all of the limitations of the base claim and any intervening claims.

The other references are cited to show other structures pertinent to Applicants' disclosure.

Any inquiry concerning this communication should be directed to Examiner Ngan Ngo at telephone number (571) 272-1711. The fax number for the Art unit is (703) 308-7722.

Any inquiry of a general nature or relating to the status of this application or proceeding should be directed to the Group receptionist whose telephone number is (703) 308-0956.

Ngan Ngo

July 7, 2004

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Ngan Van Ngo Primary Examiner